HL6331/32G

Low Operating Current Visible Laser Diode

HITACHI

ADE-208-819 (Z)
Target Specification
1st Edition
Sep. 1999

Description

The HL6331/32G are 0.63 μm band AlGaInP 10mW laser diodes with a multi-quantum well (MQW) structure. They are suitable as light sources for laser levelers, laser scanners and optical equipment for measurement.

Application

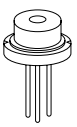
- Laser leveler
- Laser scanner
- Measurement

Features

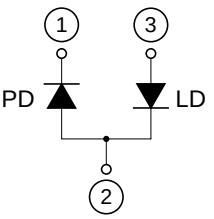
- Visible light output : 635 nm Typ
- Optical output power : 10 mW CW
- Low operating current : 55 mA Typ
- Low operating voltage : 2.4 V Max
- Operating temperature : +60°C
- TM mode oscillation

Internal Circuit

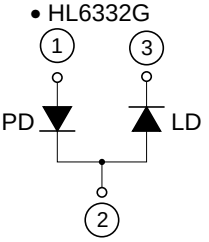
Package Type
• HL6331/32G: G2



Internal Circuit
• HL6331G



Internal Circuit
• HL6332G



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Absolute Maximum Ratings (T_C = 25°C)

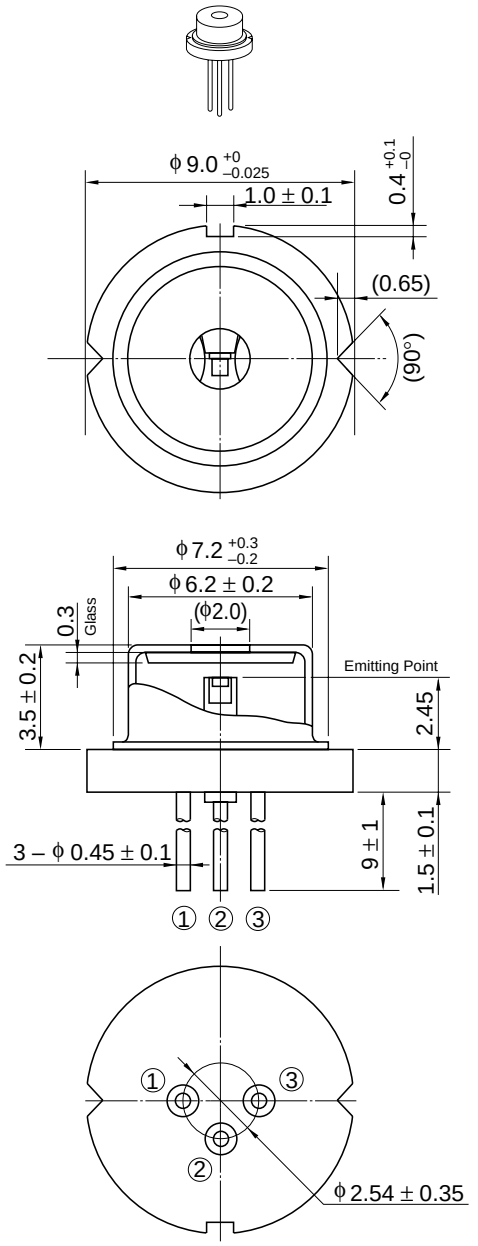
Item	Symbol	Value	Unit
Optical output power	P_O	10	mW
LD reverse voltage	$V_{R(LD)}$	2	V
PD reverse voltage	$V_{R(PD)}$	30	V
Operating temperature	Topr	–10 to +60	°C
Storage temperature	Tstg	–40 to +85	°C

Optical and Electrical Characteristics (T_C = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Optical output power	P_O	10	—	—	mW	Kink free
Threshold current	Ith	—	40	60	mA	
Operating current	I_{Op}	—	55	75	mA	P_O = 10 mW
Operating voltage	V_{OP}	—	2.2	2.4	V	P_O = 10 mW
Slope efficiency	ηs	0.3	0.6	0.9	mW/mA	6(mW) / ($I_{(8mW)}$ – $I_{(2mW)}$)
Lasing wavelength	λp	630	635	640	nm	P_O = 10 mW
Beam divergence parallel to the junction	θ//	6	8	11	deg.	P_O = 10 mW
Beam divergence parpendicular to the junction	θ⊥	25	31	36	deg.	P_O = 10 mW
Monitor current	I_S	—	0.18	—	mA	P_O = 10 mW, $V_{R(PD)}$ = 5V

Package Dimensions

Unit: mm



Hitachi Code	LD/G2
JEDEC	—
EIAJ	—
Weight (reference value)	1.1 g

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1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.

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